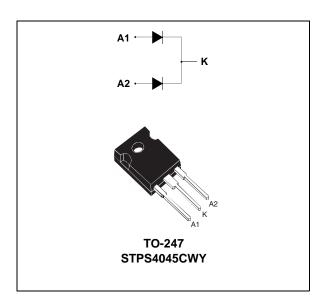


STPS4045C-Y

Automotive power Schottky rectifiers

Datasheet - production data



Description

This dual center tap Schottky rectifier is suited for switch mode power supply and high frequency DC to DC converters.

Packaged in TO-247 this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection for automotive applications.

Symbol	Value			
I _{F(AV)}	2 x 20 A			
V _{RRM}	45 V			
T _{j (max)}	175 °C			
V _{F (max)}	0.63 V			

Table 1. Device summary

Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- Avalanche capability specified
- AEC-Q101 qualified

This is information on a product in full production.

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1 Characteristics

Symbol	Parar	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	Forward rms current			30	А
1	Average forward current	$T_{c} = 150 \text{ °C}, \delta = 0.5$	Per diode	20	^
I _{F(AV)}		$T_{c} = 145 \ ^{\circ}C, \ \delta = 0.5$	Per device	40	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	220	А	
I _{RRM}	Repetitive peak reverse current	$t_p = 2 \ \mu s \ square F=1$	1	А	
I _{RSM}	Non repetitive peak reverse current	t _p = 100 µs square	3	А	
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25 \ ^\circ C$			6000	W
T _{stg}	Storage temperature range				°C
Τ _j	Operating junction temperature ⁽¹⁾			-40 to + 175	°C
dV/dt	Critical rate of rise reverse voltage			10000	V/µs

Table 2. Absolute ratings (limiting values, per diode)

1. $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

Symbol	Parameter	Value	Unit
R _{th (j-c)}	Junction to case Per diode Total	1.5 0.8	°C/W
R _{th (c)}	Coupling	0.1	

When the diodes 1 and 2 are used simultaneously:

 $\Delta \mathsf{T}_{j}(\text{diode 1}) = \mathsf{P}(\text{diode1}) \ge \mathsf{R}_{th(j\text{-}c)}(\text{Per diode}) + \mathsf{P}(\text{diode2}) \ge \mathsf{R}_{th(c)}$





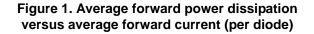
Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-	-	200	μA
		T _j = 125 °C		-	11	40	mA
V _F ⁽¹⁾		T _j = 25 °C	I⊏ = 20 A	-	-	0.76	
	Forward voltage drop	T _j = 125 °C		-	0.56	0.63	V
	Forward voltage drop	T _j = 25 °C	I _F = 40 A	-	-	0.94	v
		T _j = 125 °C	1F - 40 A	-	0.7	0.83	

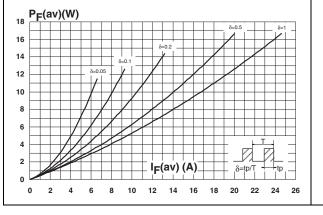
Table 4. Static electrical characteristics (per diode)

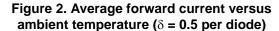
1. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.43x I_{F(AV)} + 0.01x I_{F}^{2}(RMS)$$







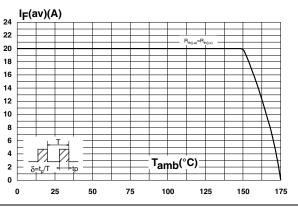


Figure 3. Normalized avalanche power derating Figure 4. Normalized avalanche power derating versus pulse duration

versus junction temperature

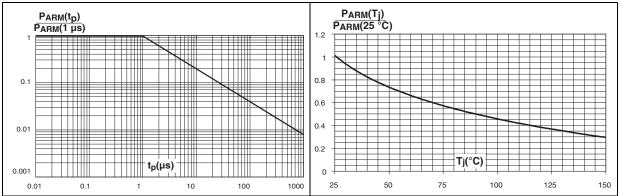
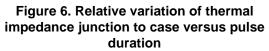




Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)



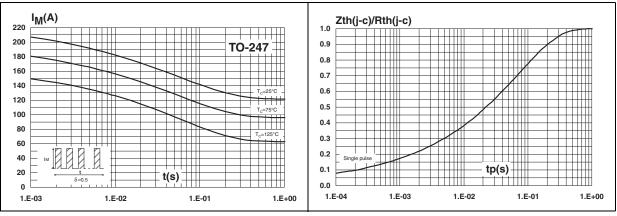
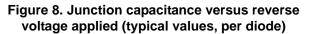


Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)



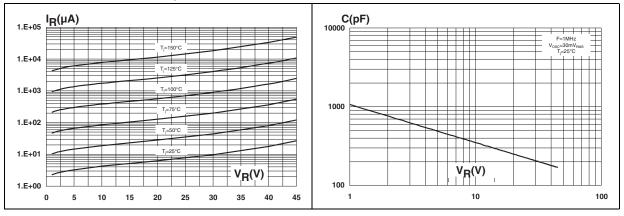
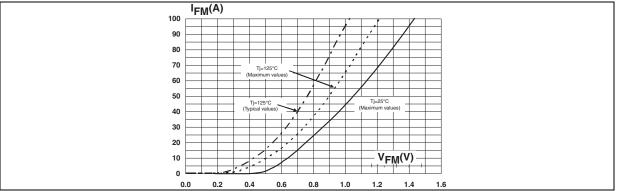


Figure 9. Forward voltage drop versus forward current (per diode)



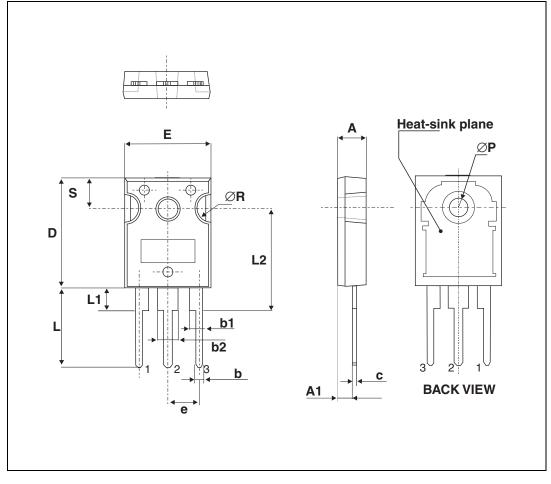


2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque values: 0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.







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	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур	Max.
А	4.85		5.15	0.191		0.203
A1	2.20		2.60	0.086		0.102
b	1.00		1.40	0.039		0.055
b1	2.00		2.40	0.078		0.094
b2	3.00		3.40	0.118		0.133
С	0.40		0.80	0.015		0.031
D ⁽¹⁾	19.85		20.15	0.781		0.793
Е	15.45		15.75	0.608		0.620
е	5.30	5.45	5.60	0.209	0.215	0.220
L	14.20		14.80	0.559		0.582
L1	3.70		4.30	0.145		0.169
L2	18.50 typ.			0.728 typ.		
ØP ⁽²⁾	3.55		3.65	0.139		0.143
ØR	4.50		5.50	0.177		0.217
S	5.30	5.50	5.70	0.209	0.216	0.224

Table 5. TO-247 dimension values

1. Dimension D plus gate protrusion does not exceed 20.5 mm

2. Resin thickness around the mounting hole is not less than 0.9 mm



3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS4045CWY	STPS4045CWY	TO-247	4.46 g	30	Tube

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
17-Dec-2013	1	First issue.



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